

## RJK6066DPP-M0

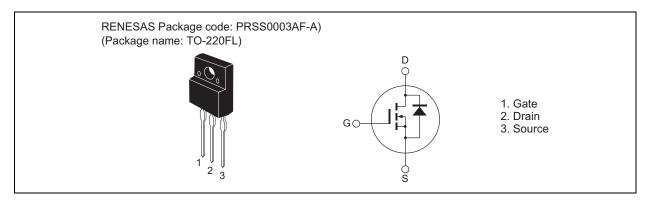
# Silicon N Channel MOS FET High Speed Power Switching

REJ03G1802-0100 Rev.1.00 Jul 02, 2009

### **Features**

- Low on-resistance
- Low leakage current
- · High speed switching

### **Outline**



### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	600	V
Gate to source voltage	V <sub>GSS</sub>	±30	V
Drain current	I <sub>D</sub> Note4	5	A
Drain peak current	I <sub>D (pulse)</sub> Note1	20	А
Body-drain diode reverse drain current	I <sub>DR</sub>	5	A
Body-drain diode reverse drain peak current	I <sub>DR</sub> (pulse) Note1	20	A
Avalanche current	I <sub>AP</sub> Note3	4	A
Avalanche energy	E <sub>AR</sub> Note3	0.87	mJ
Channel dissipation	Pch Note2	28.5	W
Channel to case thermal impedance	θch-c	4.38	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

- 2. Value at Tc = 25°C
- 3. STch =  $25^{\circ}$ C, Tch  $\leq 150^{\circ}$ C
- 4. Limited by maximum safe operation area

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### **Electrical Characteristics**

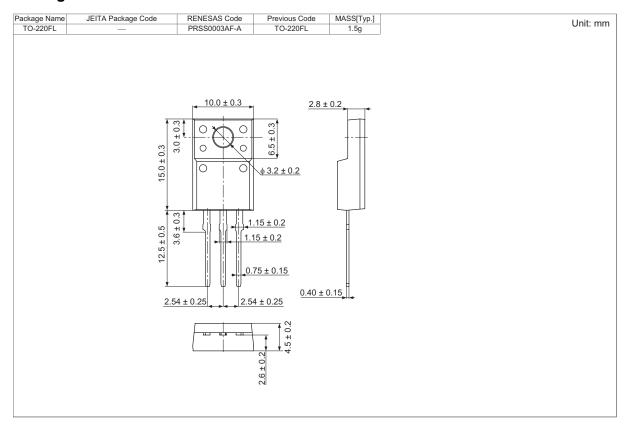
 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test conditions	
Drain to source breakdown voltage	$V_{(BR)DSS}$	600	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$	
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	1	μΑ	V <sub>DS</sub> = 600 V, V <sub>GS</sub> = 0	
Gate to source leak current	I <sub>GSS</sub>	_	_	±0.1	μΑ	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$	
Gate to source cutoff voltage	$V_{GS(off)}$	3.0	_	4.5	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$	
Static drain to source on state resistance	R <sub>DS(on)</sub>	_	2	3	Ω	$I_D = 2.5 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note5}}$	
Input capacitance	Ciss	_	425	_	pF	V <sub>DS</sub> = 25 V	
Output capacitance	Coss	_	48	_	pF	$V_{GS} = 0$	
Reverse transfer capacitance	Crss	_	6	_	pF	f = 1 MHz	
Turn-on delay time	t <sub>d(on)</sub>	_	25	_	ns	I <sub>D</sub> = 2.5 A	
Rise time	t <sub>r</sub>	_	18	_	ns	V <sub>GS</sub> = 10 V	
Turn-off delay time	t <sub>d(off)</sub>	_	51	_	ns	$R_L = 120 \Omega$	
Fall time	t <sub>f</sub>	_	13	_	ns	$Rg = 10 \Omega$	
Total gate charge	Qg	_	13.8	_	nC	V <sub>DD</sub> = 480 V	
Gate to source charge	Qgs	_	2.4	_	nC	V <sub>GS</sub> = 10 V	
Gate to drain charge	Qgd	_	7.1	_	nC	$I_D = 5 A$	
Body-drain diode forward voltage	$V_{DF}$	_	0.9	1.5	V	$I_F = 5 \text{ A}, V_{GS} = 0^{\text{Note5}}$	
Body-drain diode reverse recovery time	t <sub>rr</sub>	_	230	_	ns	$I_F = 5 \text{ A}, V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu\text{s}$	

Notes: 5. Pulse test

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### **Package Dimension**



### **Ordering Information**

Part No.	Quantity	Shipping Container
RJK6066DPP-M0-T2	1050 pcs	Box (Tube)

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